

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. <b>240428US2S</b>		SERIAL NO. <b>NEW APPLICATION</b>	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT <b>Toru TANZAWA</b>			
				FILING DATE <b>HEREWITH</b>		GROUP	
<b>U.S. PATENT DOCUMENTS</b>							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AA						
	AB						
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	AH						
	AI						
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	AL						
	AM						
	AN						
<b>FOREIGN PATENT DOCUMENTS</b>							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES NO		
	AO						
	AP						
	AQ						
	AR						
	AS						
	AT						
	AU						
	AV						
<b>OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)</b>							
DL	AW	M. BAUER, et al. "A MULTILEVEL-CELL 32MB FLASH MEMORY," 1995 IEEE International Solid-State Circuits Conference, Digest of Technical Papers, February 1995, pgs. 132-133.					
DL	AX	G. CAMPARDO, et al. "A 40MM <sup>2</sup> 3V 50MHZ 64MB 4-LEVEL CELL NOR-TYPE FLASH MEMORY," 2000 IEEE International Solid-State Circuits Conference, Digest of Technical Papers, February 2000, pgs. 274-275.					
DL	AY	D. ELMHURST, et al. "A 1.8V 128MB 125 MHZ MULTI-LEVEL CELL FLASH MEMORY WITH FLEXIBLE READ WHILE WRITE," ISSCC 2003 Digest of Technical Papers, February 2003, pgs. 286-287.					
	AZ					<input type="checkbox"/> Additional References sheet(s) attached	
Examiner					Date Considered <b>7/04</b>		
<small>*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.</small>							